PJE840	3						
20V P-Chan Voltage	nel Enhanc -20 V	ement Mode	MOSFET	– ESI	D Protecte SOT-523	0.052(1.30)	Unit : inch(mm)
Features						0.043(1.10) (2000 0 (2000 0 (2000 0 (2000 0 (2000 0 (2000 0)) (2000 0 (2000 0)) (2000 0) (2000 0) (200 0) (2000	0.024(0.60) 0.019(0.50)
• RDS(ON) , V	/GS@-4.5V, ID@	2-0.6A<340mΩ		_	0.067(1.70) 0.059(1.50) 0.044(1.10) 0.035(0.90)		
 RDS(ON) , VGS@-2.5V, ID@-0.4A<420mΩ 							
 RDS(ON), VGS@-1.8V, ID@-0.2A<600mΩ 					0.007(0.17) 0.002(0.07)		
Advanced Trench Process Technology							
Specially Designed for Switch Load, PWM Application, etc.					0.067(1.70) 0.059(1.50)		
ESD Protected 2KV HBM							
 Lead free in compliance with EU RoHS 2.0 							
Green molding compound as per IEC 61249 standard					0.012(0.30) 0.004(0.10)		
Mechanical Data				_		D 3	
Case : SOT-523 Package							
• Terminals : Solderable per MIL-STD-750, Method 2026							
 Approx. Weight : 0.002 grams 						• ,••	

• Marking : E03

Maximum Ratings and Thermal Characteristics (T_A=25^oC unless otherwise noted)

PARAMET	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V _{DS}	-20	V	
Gate-Source Voltage	V _{GS}	<u>+</u> 8	V	
Continuous Drain Current	ID	-0.6	А	
Pulsed Drain Current	I _{DM}	-2.4	А	
	T _a =25°C		300	mW
Power Dissipation	Derate above 25°C		2.4	mW/ºC
Operating Junction and Storage 1	TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient ^(Note 3)	Reja	417	∘C/W	

1 G 2 S



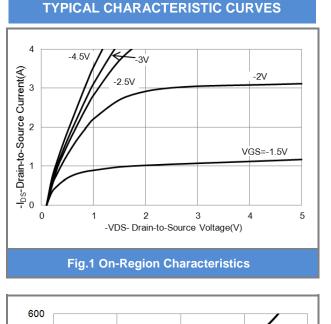
Electrical Characteristics (T_A=25°C unless otherwise noted)

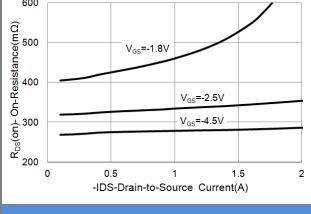
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =-250uA		-20	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{GS(th)} V _{DS} =V _{GS} , I _D =-250uA		-0.64	-1.0	V	
		V _{GS} =-4.5V, I _D =-0.6A	-	280	340		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-2.5V, I _D =-0.4A	-	330	420	mΩ	
		V _{GS} =-1.8V, I _D =-0.2A	-	420	600		
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-20V, V _{GS} =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 3.5	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	Qg		-	2.2	-	nC	
Gate-Source Charge	Qgs	V _{DS} =-10V, I _D =-0.6A, V _{GS} =-4.5V ^(Note 1,2)	-	0.4	-		
Gate-Drain Charge	Q_{gd}	V _{GS} =-4.5V ^(1000-1,2)	-	0.5	-		
Input Capacitance	Ciss		-	151	-	pF	
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	27	-		
Reverse Transfer Capacitance	Crss	I=1.0MHZ	-	9	-		
Switching							
Turn-On Delay Time	urn-On Delay Time td _(on)		-	9	-		
Turn-On Rise Time	tr	V_{DD} =-10V, I_{D} =-0.6A,	-	37	-	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=-4.5V$,	-	128	-		
Turn-Off Fall Time	tf	$R_G=6\Omega^{(Note 1,2)}$	-	72	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	s				-0.4	Α	
Diode Forward Current			-	-	-0.4	A	
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.95	-1.2	V	

NOTES :

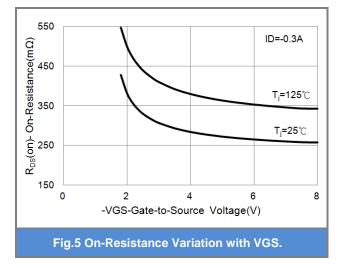
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited

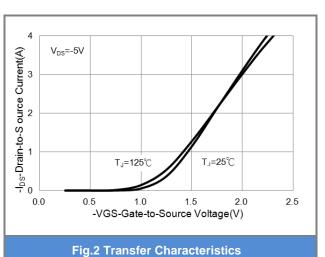












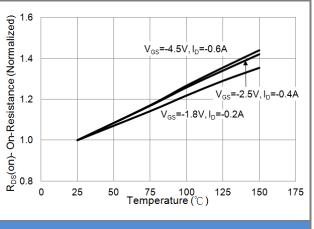
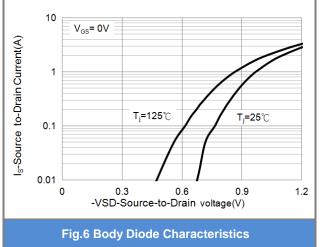
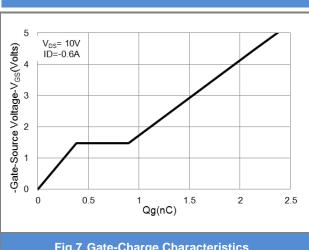


Fig.4 On-Resistance vs. Junction temperature







TYPICAL CHARACTERISTIC CURVES

Fig.7 Gate-Charge Characteristics

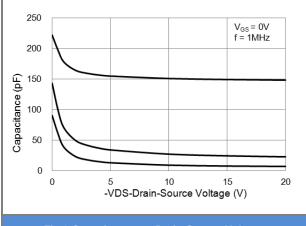


Fig.9 Capacitance vs. Drain-Source Voltage

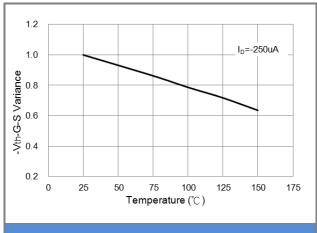


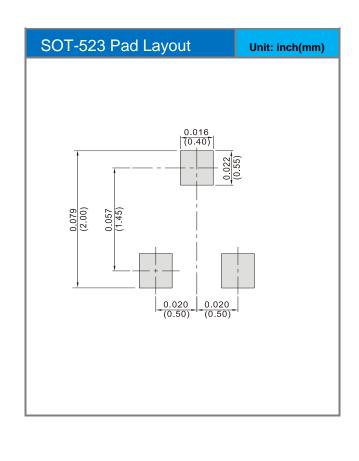
Fig.8 Threshold Voltage Variation with Temperature



Product and Packing Information

Part No.	Package Type	Packing Type	Marking		
PJE8403	SOT-523	4K pcs / 7" reel	E03		

Mounting Pad Layout





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